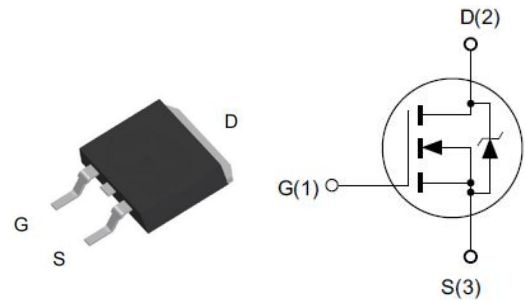


Features

- ◆ 68V, 88A, $R_{DS(on)}$ (Typ.) = 6.0m Ω @ $V_{GS} = 10V$
- ◆ Excellent $R_{DS(on)}$ and Low Gate Charge
- ◆ 100% E_{AS} Guaranteed
- ◆ Halogen-free; RoHS-compliant

Application

- ◆ Load Switch
- ◆ PWM Application
- ◆ Power Management



Absolute Maximum Ratings $T_c = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Rating	Unit
V_{DS}	Drain-Source Voltage ^a	68	V
V_{GS}	Gate-Source Voltage	± 20	
I_D	Drain Current-Continuous	$T_C = 25^\circ\text{C}$	A
		$T_C = 100^\circ\text{C}$	
I_{DM}	Drain Current-Pulsed ^b	320	
P_D	Power Dissipation, $T_C = 25^\circ\text{C}$	109	W
E_{AS}	Single Pulsed Avalanche Energy ^c	342	mJ
T_J, T_{STG}	Operating and Store Temperature Range	150, -55 to 150	$^\circ\text{C}$

Thermal Characteristics

Symbol	Parameter	Value	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case	1.15	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	62.5	

Electrical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

■ Off Characteristics

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	68	-	-	V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 68V, V_{GS} = 0V$	-	-	1.0	μA
I_{GSS}	Forward Gate Body Leakage Current	$V_{DS} = 0V, V_{GS} = \pm 20V$	-	-	± 100	nA

■ On Characteristics

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu A$	2.0	-	4.0	V
$R_{DS(on)}$	Static Drain-Source On-Resistance ^d	$V_{GS} = 10V, I_D = 40A$	-	6.0	7.8	mΩ
		$V_{GS} = 6.0V, I_D = 30A$	-	8.5	11	

■ Dynamic Characteristics

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
R_G	Gate Resistance	$V_{DS} = V_{GS} = 0V,$ $f = 1.0MHz$	-	2.0	-	Ω
C_{iss}	Input Capacitance	$V_{DS} = 25V,$ $V_{GS} = 0V,$ $f = 1.0MHz$	-	3601	-	pF
C_{oss}	Output Capacitance		-	318	-	
C_{rss}	Reverse Transfer Capacitance		-	299	-	

■ On Characteristics

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 35V,$ $V_{GS} = 10V,$ $I_D = 40A,$ $R_{GEN} = 4.7\Omega$	-	20	-	ns
t_r	Turn-On Rise Time		-	51	-	
$t_{d(off)}$	Turn-Off Delay Time		-	50	-	
t_f	Turn-Off Fall Time		-	22	-	
Q_g	Total Gate Charge	$V_{DS} = 35V,$ $V_{GS} = 0 \text{ to } 10V,$ $I_D = 40A$	-	75	-	nC
Q_{gs}	Gate-Source Charge		-	26	-	
Q_{gd}	Gate-Drain Charge		-	20	-	

■ Drain-Source Diode Characteristics

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
I_S	Drain-Source Diode Forward Continuous Current	$V_G = V_D = 0V,$ Force Current	-	-	88	A
I_{SM}	Maximum Pulsed Current		-	-	320	
V_{SD}	Drain-Source Diode Forward Voltage	$V_{GS} = 0V, I_S = 30A$	-	-	1.1	V
T_{rr}	Body Diode Reverse Recovery Time	$I_F = 20A,$ $di_F/dt = 100A/\mu s$	-	23	-	ns
Q_{rr}	Body Diode Reverse Recovery Charge	$I_F = 20A,$ $di_F/dt = 100A/\mu s$	-	16	-	nC

Notes:

- $T_J = +25^\circ C$ to $+150^\circ C$.
- Repetitive rating: pulse width limited by maximum junction temperature.
- $L = 0.5mH, V_{DD} = 25V, I_{AS} = 37A, R_G = 25\Omega$ Starting $T_J = 25^\circ C$.
- Pulse width $\leq 300\mu s$; duty cycle $\leq 0.5\%$.

Characteristic Curve

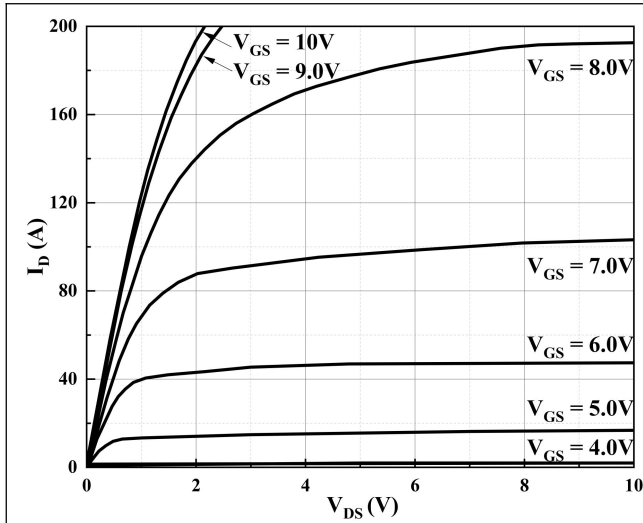


Figure 1. Typical Output Characteristics

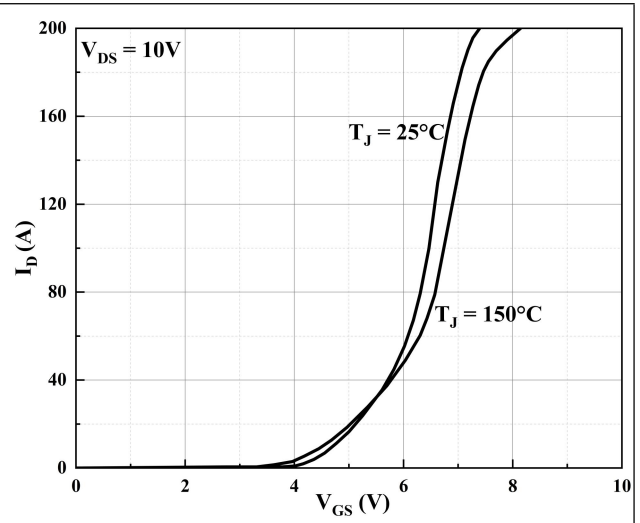


Figure 2. Typical Transfer Characteristics

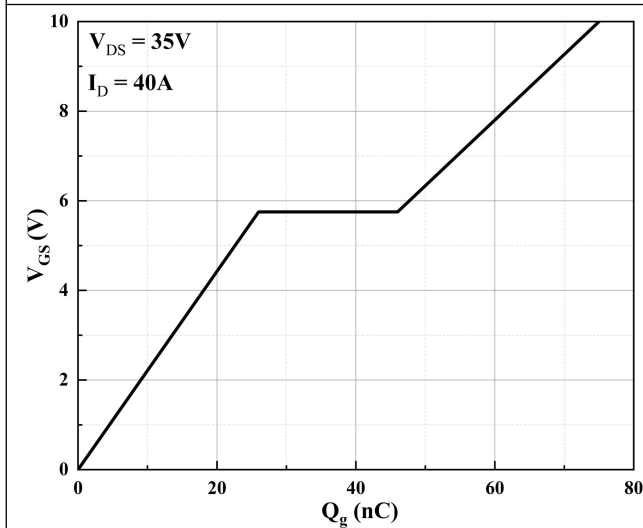


Figure 3. Typical Gate Charge

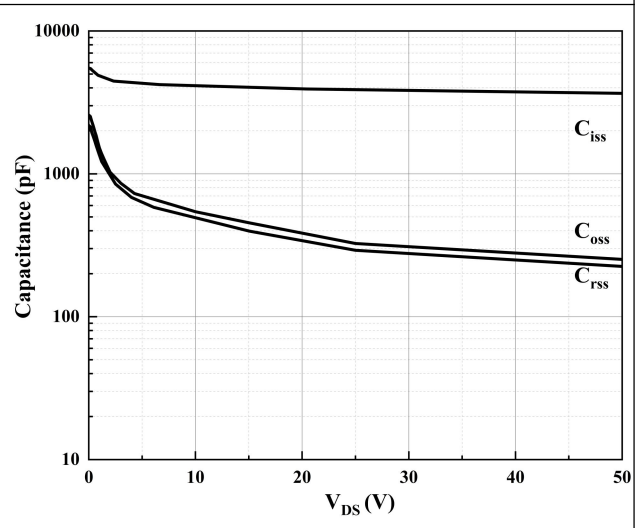


Figure 4. Typical Capacitance

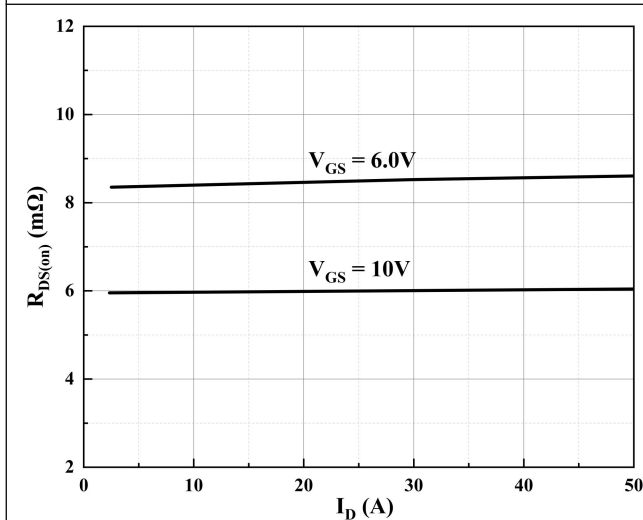


Figure 5. Static Drain-Source On-Resistance vs. Drain Current

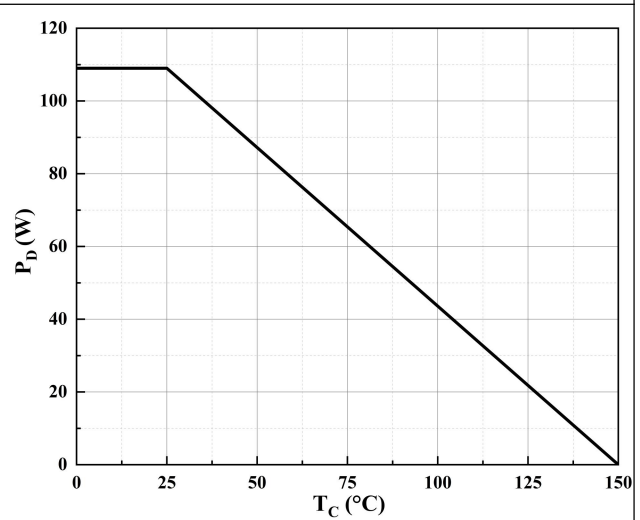


Figure 6. Power Dissipation vs. Case Temperature

Characteristic Curve

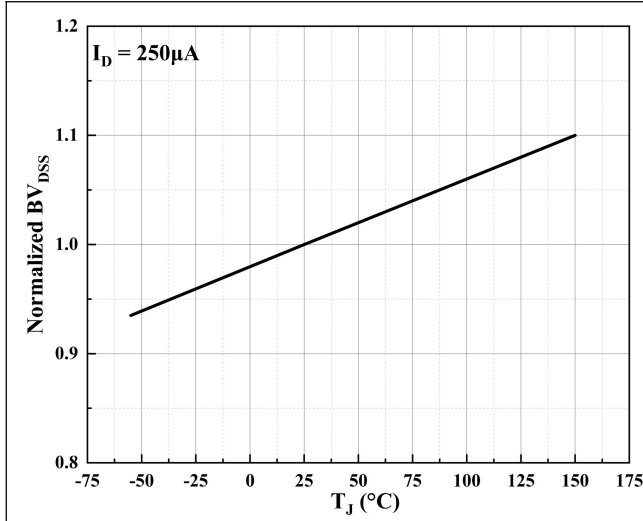


Figure 7. Normalized Breakdown Voltage vs. Junction Temperature

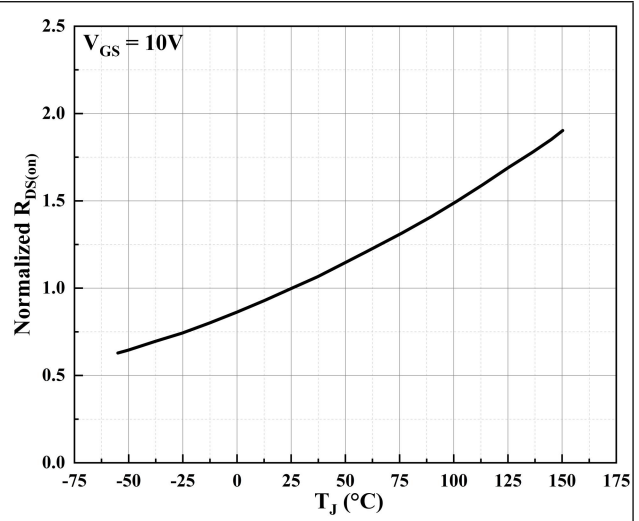


Figure 8. Normalized Static Drain-Source On-Resistance vs. Junction Temperature

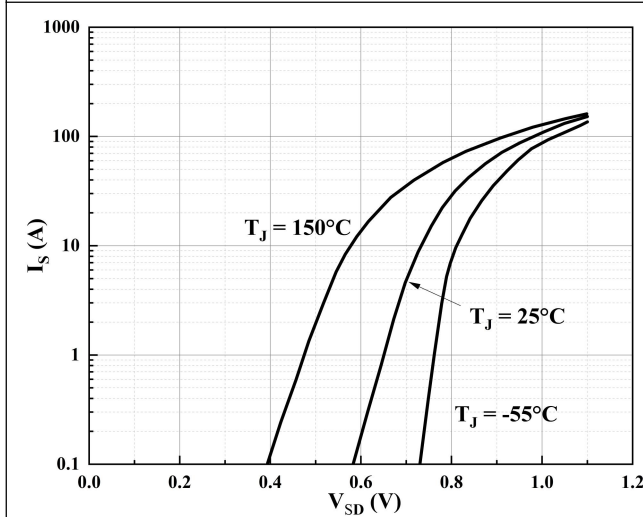


Figure 9. Body Diode Characteristics

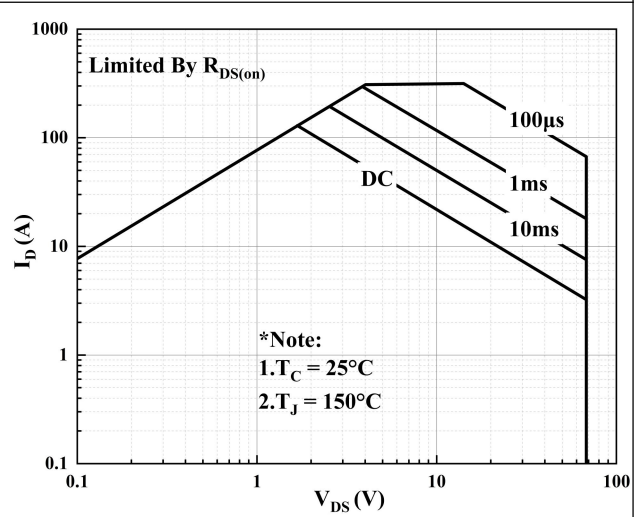


Figure 10. Safe Operating Area

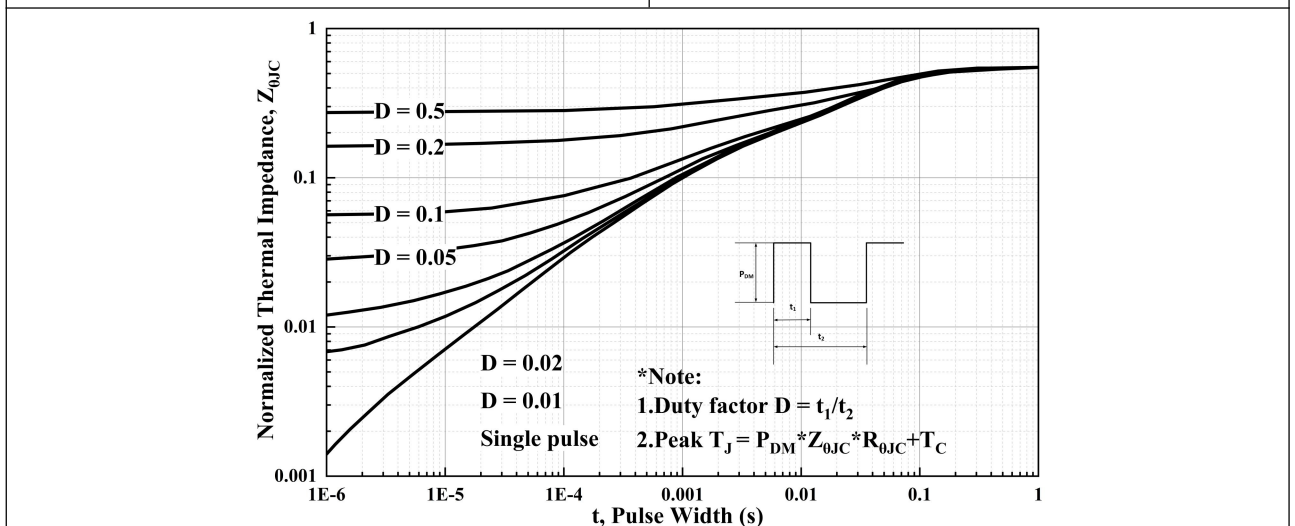
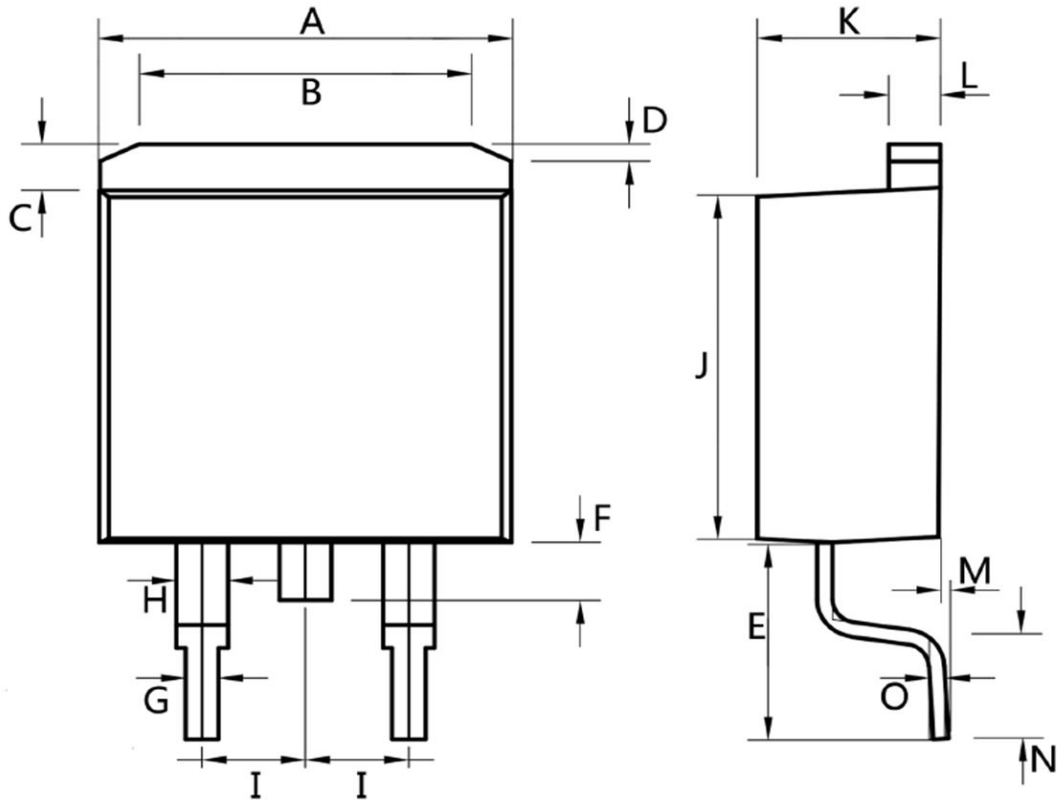


Figure 11. Gate Threshold Voltage vs. Junction Temperature

■ Package Information

TO-263



Dim.	Min.	Max.
A	10.15	10.35
B	6	8
C	1.2	1.5
D	0.55	1.0
E	4.3	5.3
F	1.4	1.6
G	0.75	0.85
H	1.2	1.5
I	Typ2.54	
J	8.5	9.5
K	4.3	4.55
L	1.25	1.35
M	0.02	0.23
N	2.2	2.8
O	0.35	0.45
All Dimensions in millimeter		